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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM7®
Core Size	32-Bit Single-Core
Speed	60MHz
Connectivity	CANbus, I²C, SPI, SSI, SSP, UART/USART, USB
Peripherals	DMA, PWM, WDT
Number of I/O	72
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/str750fv0t6

3 Introduction

This Datasheet contains the description of the STR750F family features, pinout, Electrical Characteristics, Mechanical Data and Ordering information.

For complete information on the Microcontroller memory, registers and peripherals. Please refer to the STR750F Reference Manual.

For information on the ARM7TDMI-S core please refer to the ARM7TDMI-S Technical Reference Manual available from Arm Ltd.

For information on programming, erasing and protection of the internal Flash memory please refer to the STR7 Flash Programming Reference Manual

For information on third-party development tools, please refer to the http://www.st.com/mcu website.

3.1 Functional description

The STR750F family includes devices in 2 package sizes: 64-pin and 100-pin. Both types have the following common features:

ARM7TDMI-S™ core with embedded Flash & RAM

STR750F family has an embedded ARM core and is therefore compatible with all ARM tools and software. It combines the high performance ARM7TDMI-S™ CPU with an extensive range of peripheral functions and enhanced I/O capabilities. All devices have on-chip high-speed single voltage FLASH memory and high-speed RAM.

Figure 1 shows the general block diagram of the device family.

Embedded Flash memory

Up to 256 KBytes of embedded Flash is available in Bank 0 for storing programs and data. An additional Bank 1 provides 16 Kbytes of RWW (Read While Write) memory allowing it to be erased/programmed on-the-fly. This partitioning feature is ideal for storing application parameters.

- When configured in burst mode, access to Flash memory is performed at CPU clock speed with 0 wait states for sequential accesses and 1 wait state for random access (maximum 60 MHz).
- When not configured in burst mode, access to Flash memory is performed at CPU clock speed with 0 wait states (maximum 32 MHz)

Embedded SRAM

16 Kbytes of embedded SRAM accessed (read/write) at CPU clock speed with 0 wait states.

Enhanced interrupt controller (EIC)

In addition to the standard ARM interrupt controller, the STR750F embeds a nested interrupt controller able to handle up to 32 vectors and 16 priority levels. This additional hardware block provides flexible interrupt management features with minimal interrupt latency.

Serial memory interface (SMI)

The Serial Memory interface is directly able to access up to 4 serial FLASH devices. It can be used to access data, execute code directly or boot the application from external memory. The memory is addressed as 4 banks of up to 16 Mbytes each.

Clocks and start-up

After RESET or when exiting from Low Power Mode, the CPU is clocked immediately by an internal RC oscillator (FREEOSC) at a frequency centered around 5 MHz, so the application code can start executing without delay. In parallel, the 4/8 MHz Oscillator is enabled and its stabilization time is monitored using a dedicated counter.

An oscillator failure detection is implemented: when the clock disappears on the XT1 pin, the circuit automatically switches to the FREEOSC oscillator and an interrupt is generated.

In Run mode, the AHB and APB clock speeds can be set at a large number of different frequencies thanks to the PLL and various prescalers: up to 60 MHz for AHB and up to 32 MHz for APB when fetching from Flash (64 MHz and 32 MHz when fetching from SRAM).

In SLOW mode, the AHB clock can be significantly decreased to reduce power consumption.

The built-in Clock Controller also provides the 48 MHz USB clock directly without any extra oscillators or PLL. For instance, starting from the 4 MHz crystal source, it is possible to obtain in parallel 60 MHz for the AHB clock, 48 MHz for the USB clock and 30 MHz for the APB peripherals.

Boot modes

At start-up, boot pins are used to select one of five boot options:

- Boot from internal flash
- Boot from external serial Flash memory
- Boot from internal boot loader
- Boot from internal SRAM

Booting from SMI memory allows booting from a serial flash. This way, a specific boot monitor can be implemented. Alternatively, the STR750F can boot from the internal boot loader that implements a boot from UART.

Power supply schemes

You can connect the device in any of the following ways depending on your application.

- **Power Scheme 1: Single external 3.3V power source**. In this configuration the V_{CORE} supply required for the internal logic is generated internally by the main voltage regulator and the V_{BACKUP} supply is generated internally by the low power voltage regulator. This scheme has the advantage of requiring only one 3.3V power source.
- **Power Scheme 2: Dual external 3.3V and 1.8V power sources.** In this configuration, the internal voltage regulators are switched off by forcing the VREG_DIS pin to high level. V_{CORE} is provided externally through the V_{18} and V_{18REG} power pins and V_{BACKUP} through the V_{18_BKP} pin. This scheme is intended to save power consumption for applications which already provide an 1.8V power supply.
- **Power Scheme 3: Single external 5.0V power source.** In this configuration the V_{CORE} supply required for the internal logic is generated internally by the main voltage

Figure 3. LQFP64 pinout

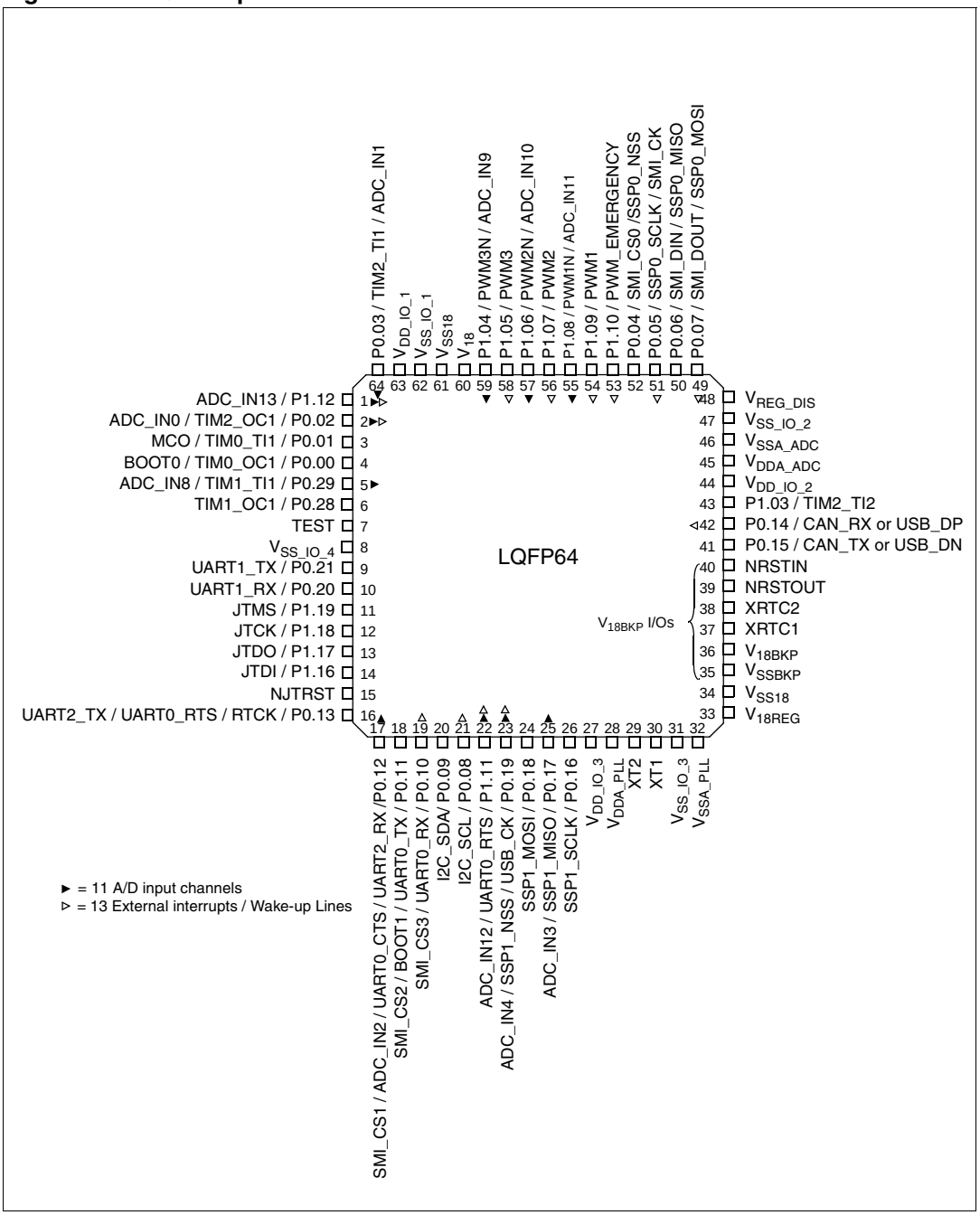


Table 4. LFBGA100 ball connections

	1	2	3	4	5	6	7	8	9	10
A	P0.03	P1.13	P1.14	P1.04	P1.06	P1.08	P0.05	P0.06	P0.07	P1.02
B	P1.12	P0.02	P0.01	P1.05	P1.07	P1.09	P0.04	P2.13	P1.03	P2.10
C	P0.31	P0.00	V_{DD_IO}	V_{18}	P1.10	P2.09	V_{SS_IO}	V_{SSA_ADC}	P2.11	USB_DP
D	P0.29	P0.30	V_{SS_IO}	V_{SS18}	P1.01	P1.15	V_{DD_IO}	V_{DDA_ADC}	P2.12	USB_DN
E	P0.28	P0.23	P0.22	V_{SS_IO}	TEST	P1.00	NRSTOUT	VREG_DIS	NRSTIN	P0.14
F	P2.03	P0.21	P0.20	P2.02	P2.04	P2.05	P2.06	V_{SS18}	V_{SSBKP}	P0.15
G	NJTRST	P1.18	P1.19	P2.01	P2.00	P2.07	2.08	V_{18REG}	V_{18BKP}	XRTC2
H	P0.13	P1.16	P1.17	P2.19	P2.18	P2.17	P0.24	P2.14	P2.16	XRTC1
J	P0.11	P0.12	P1.11	P0.27	P0.19	P0.26	P0.25	P2.15	V_{DD_IO}	V_{SS_IO}
K	P0.10	P0.09	P0.08	P0.18	P0.17	P0.16	XT1	XT2	V_{DDA_PLL}	V_{SSA_PLL}

Table 5. LFBGA64 ball connections

	1	2	3	4	5	6	7	8
A	P0.03	V_{SS_IO}	P1.04	P1.06	P1.08	P0.05	P0.06	P0.07
B	P1.12	V_{DD_IO}	P1.05	P1.07	P1.09	P0.04	P1.10	P1.03
C	P0.01	P0.02	P0.00	V_{18}	V_{SS18}	V_{DD_IO}	V_{SS_IO}	P0.14
D	P0.29	P0.28	TEST	V_{SS_IO}	VREG_DIS	V_{DDA_ADC}	V_{SSA_ADC}	P0.15
E	P1.18	P1.19	P0.20	P0.21	NRSTOUT	NRSTIN	V_{18BKP}	XRTC2
F	P0.13	NJTRST	P1.16	P1.17	V_{18REG}	V_{SS18}	V_{SSBKP}	XRTC1
G	P0.11	P0.12	P1.11	P0.19	V_{DD_IO}	V_{SS_IO}	V_{DDA_PLL}	V_{SSA_PLL}
H	P0.10	P0.09	P0.08	P0.17	P0.18	P0.16	XT2	XT1

Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function	
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP				
7	D1	5	D1	P0.29 / TIM1_TI1 / ADC_IN8	I/O	T_T	**X**	X		O2	X	X		**Port 0.29**	TIM1: Input Capture 1	ADC: Analog input 8
8	E1	6	D2	P0.28 / TIM1_OC1	I/O	T_T	**X**	X		O2	X	X		**Port 0.28**	TIM1: Output Compare 1	
9	E5	7	D3	TEST	I									Reserved, must be tied to ground		
10	E4	8	D4	VSS_IO	S									Ground Voltage for digital I/Os		
11	E2			P0.23 / UART1_RTS / ADC_IN6	I/O	T_T	**X**	X		O2	X	X		**Port 0.23**	UART1: Ready To Send output(4)	ADC analog input 6
12	F5			P2.04 / TIM2_OC1	I/O	T_T	**X**	X		O2	X	X		**Port 2.04**	TIM2: Output Compare 1(4)	
13	F1			P2.03 / UART1_RTS	I/O	T_T	**X**	X		O2	X	X		**Port 2.03**	UART1: Ready To Send output(4)	
14	F4			P2.02	I/O	T_T	**X**	X		O2	X	X		**Port 2.02**		
15	E3			P0.22 / UART1_CTS / ADC_IN5	I/O	T_T	**X**	X		O2	X	X		**Port 0.22**	UART1: Clear To Send input	ADC: Analog input 5
16	F2	9	E4	P0.21 / UART1_TX	I/O	T_T	**X**	X		O2	X	X		**Port 0.21**	UART1: Transmit data output (remappable to P0.15)(4)	
17	F3	10	E3	P0.20 / UART1_RX	I/O	T_T	**X**	X		O2	X	X		**Port 0.20**	UART1: Receive data input (remappable to P0.14)(4)	
18	G3	11	E2	P1.19 / JTMS	I/O	T_T	X	X		O2	X	X		**JTAG mode selection input(6)**	Port 1.19	
19	G2	12	E1	P1.18 / JTCK	I/O	T_T	X	X		O2	X	X		**JTAG clock input(6)**	Port 1.18	
20	H3	13	F4	P1.17 / JTDO	I/O	T_T	X	X		O8	X	X		**JTAG data output(6)**	Port 1.17	
21	H2	14	F3	P1.16 / JTDI	I/O	T_T	X	X		O2	X	X		**JTAG data input(6)**	Port 1.16	
22	G1	15	F2	NJTRST	I	T_T								JTAG reset input(5)		
23	G4			P2.01	I/O	T_T	**X**	X		O2	X	X		**Port 2.01**		
24	G5			P2.00	I/O	T_T	**X**	X		O2	X	X		**Port 2.00**		
25	H1	16	F1	P0.13 / RTCK / UART0_RTS UART2_TX	I/O	T_T	X	X		O8	X	X		**JTAG return clock output(6)**	Port 0.13 / UART0: Ready To Send output(4)	UART2: Transmit Data output (when remapped)(8)

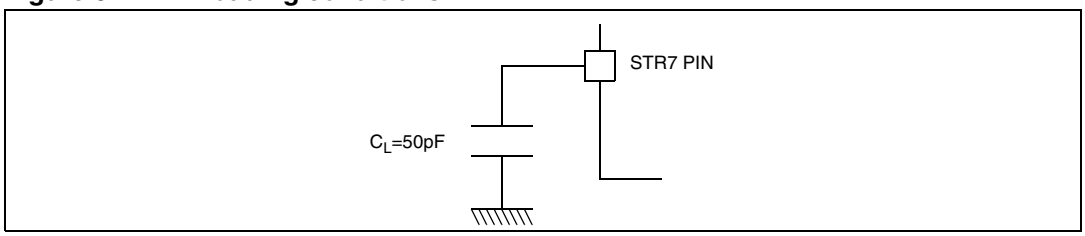
Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function	
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP				
68	A10			P1.02 / TIM2_OC2	I/O	T_T	X	X		O2	X	X		**Port 1.02**	TIM2: Output compare 2 (remappable to P0.06)(8)	
69	D7	44	C6	VDD_IO	S									Supply Voltage for digital I/Os		
70	D8	45	D6	VDDA_ADC	S									Supply Voltage for A/D converter		
71	C9			P2.11	I/O	T_T	X	X		O2	X	X		**Port 2.11**		
72	B10			P2.10	I/O	T_T	X	X		O2	X	X		**Port 2.10**		
73	C8	46	D7	VSSA_ADC	S									Ground Voltage for A/D converter		
74	C7	47	C7	VSS_IO	S									Ground Voltage for digital I/Os		
75	E8	48	D5	VREG_DIS	I	T_T								Voltage Regulator Disable input		
76	A9	49	A8	P0.07 / SMI_DOUT / SSP0_MOSI	I/O	T_T	X	X	EIT2	O4	X	X		**Port 0.07**	Serial Memory Interface: data output	SSP0: Master out Slave in data
77	A8	50	A7	P0.06 / SMI_DIN / SSP0_MISO	I/O	T_T	X	X		O4	X	X		**Port 0.06**	Serial Memory Interface: data input	SSP0: Master in Slave out data
78	A7	51	A6	P0.05 / SSP0_SCLK / SMI_CK	I/O	T_T	X	X	EIT1	O4	X	X		**Port 0.05**	SSP0: Serial clock	Serial Memory Interface: Serial clock output
79	B7	52	B6	P0.04 / SMI_CS0 / SSP0_NSS	I/O	T_T	X	X		O4	X	X		**Port 0.04**	Serial Memory Interface: chip select output 0	SSP0: Slave select input
80	C5	53	B7	P1.10 PWM_EMERGENCY	I/O	T_T	X	X	EIT10	O2	X	X		**Port 1.10**	PWM: Emergency input	
81	B6	54	B5	P1.09 / PWM1	I/O	T_T	X	X	EIT9	O4	X	X		**Port 1.09**	PWM: PWM1 output	
82	C6			P2.09 / PWM1N	I/O	T_T	X	X		O2	X	X		**Port 2.09**	PWM: PWM1 complementary output(4)	
83	G7			P2.08 / PWM2	I/O	T_T	X	X		O2	X	X		**Port 2.08**	PWM: PWM2 output(4)	
84	G6			P2.07 / PWM2N	I/O	T_T	X	X		O2	X	X		**Port 2.07**	PWM: PWM2 complementary output(4)	
85	F7			P2.06 / PWM3	I/O	T_T	X	X		O2	X	X		**Port 2.06**	PWM: PWM3 output(4)	
86	F6			P2.05 / PWM3N	I/O	T_T	X	X		O2	X	X		**Port 2.05**	PWM: PWM3 complementary output(4)	
87	A6	55	A5	P1.08 / PWM1N / ADC_IN11	I/O	T_T	X	X		O4	X	X		**Port 1.08**	PWM: PWM1 complementary output(8)	ADC: analog input 11
88	B5	56	B4	P1.07 / PWM2	I/O	T_T	X	X	EIT8	O4	X	X		**Port 1.07**	PWM: PWM2 output(4)	
89	A5	57	A4	P1.06 / PWM2N / ADC_IN10	I/O	T_T	X	X		O4	X	X		**Port 1.06**	PWM: PWM2 complementary output(4)	ADC: analog input 10
90	B4	58	B3	P1.05 / PWM3	I/O	T_T	X	X	EIT7	O4	X	X		**Port 1.05**	PWM: PWM3 output(4)	

6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 6*.

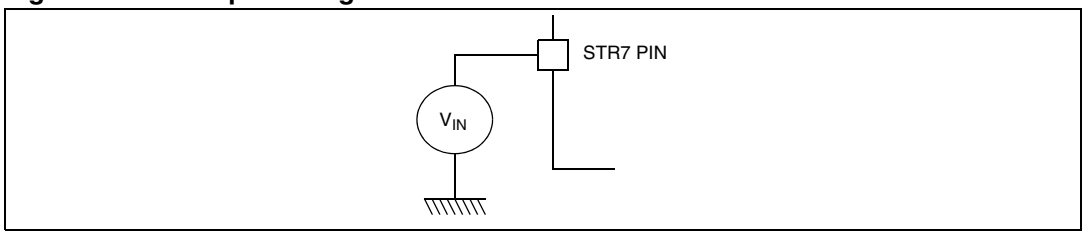
Figure 6. Pin loading conditions



6.1.5 Pin input voltage

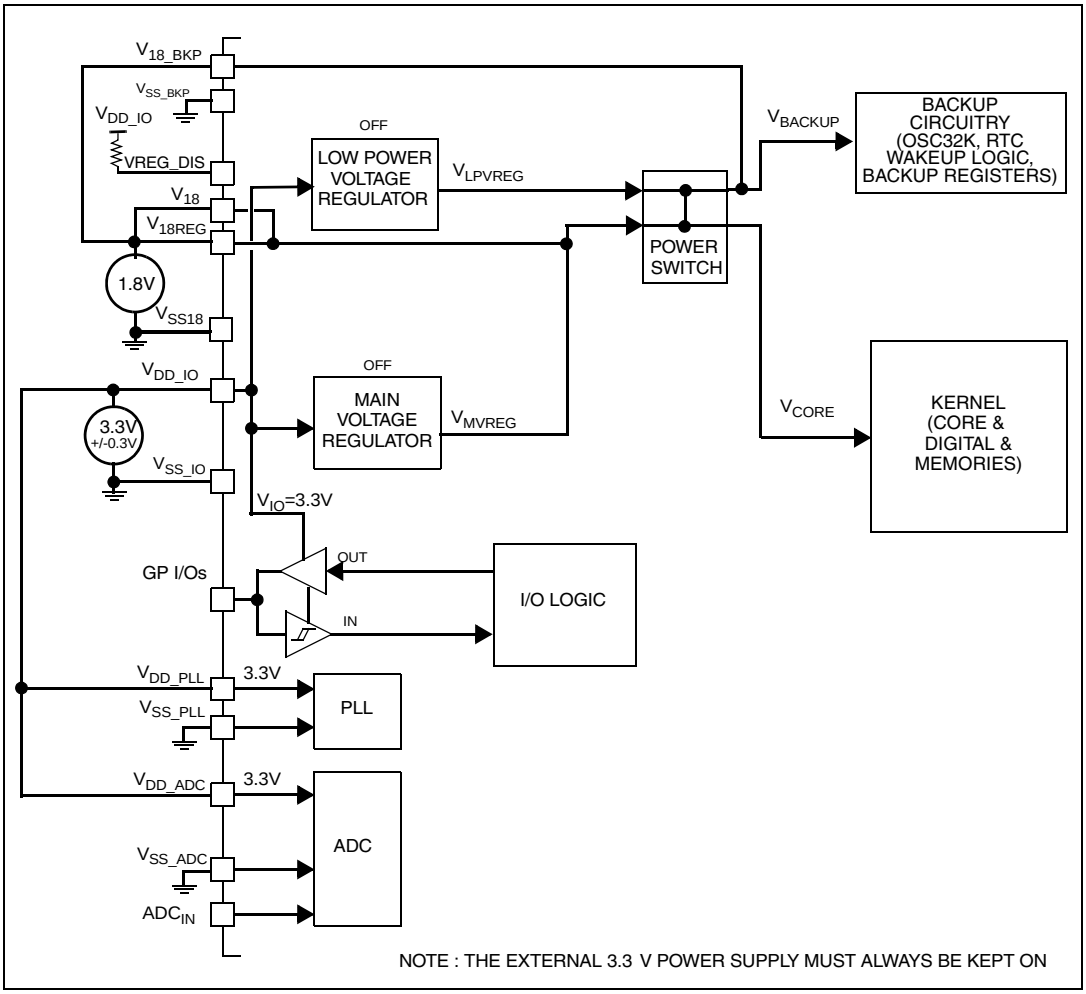
The input voltage measurement on a pin of the device is described in *Figure 7*.

Figure 7. Pin input voltage



Power supply scheme 2: Dual external 1.8V and 3.3V supply

Figure 9. Power supply scheme 2



6.2.2 Current characteristics

Table 8. Current characteristics

Symbol	Ratings	Maximum value	Unit
I_{VDD_IO} (1)	Total current into V_{DD_IO} power lines (source) (2)	150	mA
I_{VSS_IO} (1)	Total current out of V_{SS} ground lines (sink) (2)	150	
I_{IO}	Output current sunk by any I/O and control pin	25	
	Output current source by any I/Os and control pin	- 25	
$I_{INJ(PIN)}$ (3) & (4)	Injected current on NRSTIN pin	± 5	
	Injected current on XT1 and XT2 pins	± 5	
	Injected current on any other pin (5)	± 5	
$\Sigma I_{INJ(PIN)}$ (3)	Total injected current (sum of all I/O and control pins) (5)	± 25	

1. The user can use GPIOs to source or sink high current (up to 20 mA for O8 type High Sink I/Os). In this case, the user must ensure that these absolute max. values are not exceeded (taking into account the RUN power consumption) and must follow the rules described in *Section 6.3.8: I/O port pin characteristics on page 54*.
2. All 3.3 V or 5.0 V power (V_{DD_IO}, V_{DDA_ADC}, V_{DDA_PLL}) and ground (V_{SS_IO}, V_{SSA_ADC}, V_{DDA_ADC}) pins must always be connected to the external 3.3V or 5.0V supply.
3. $I_{INJ(PIN)}$ must never be exceeded. This is implicitly insured if V_{IN} maximum is respected. If V_{IN} maximum cannot be respected, the injection current must be limited externally to the $I_{INJ(PIN)}$ value. A positive injection is induced by $V_{IN}>V_{DD}$ while a negative injection is induced by $V_{IN}<V_{SS}$. Data based on T_A=25°C.
4. Negative injection disturbs the analog performance of the device. See note in *Section 6.3.12: 10-bit ADC characteristics on page 72*.
5. When several inputs are submitted to a current injection, the maximum $\Sigma I_{INJ(PIN)}$ is the absolute sum of the positive and negative injected currents (instantaneous values). These results are based on characterization with $\Sigma I_{INJ(PIN)}$ maximum current injection on four I/O port pins of the device.

6.2.3 Thermal characteristics

Table 9. Thermal characteristics

Symbol	Ratings	Value	Unit
T_{STG}	Storage temperature range	-65 to +150	°C
T_J	Maximum junction temperature	150	°C

Figure 16. Power consumption in STOP mode in Single supply scheme (3.3 V range)

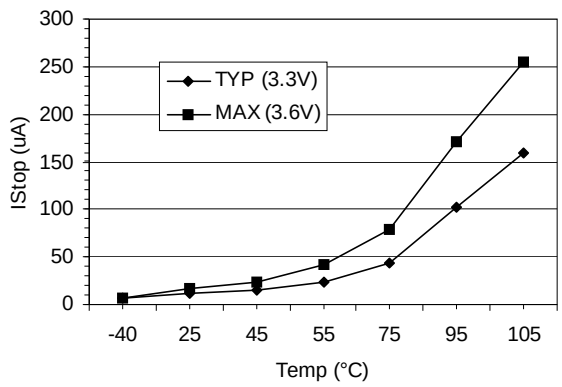


Figure 17. Power consumption in STOP mode Single supply scheme (5 V range)

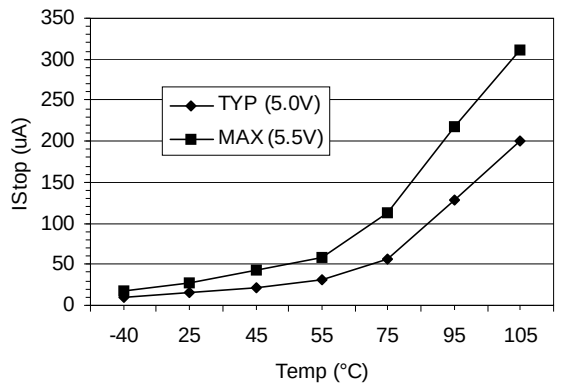


Figure 18. Power consumption in STANDBY mode (3.3 V range)

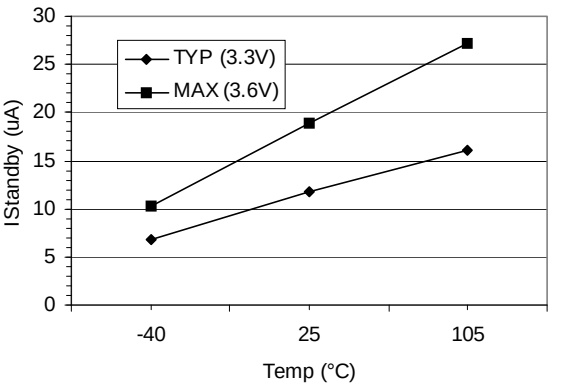


Figure 19. Power consumption in STANDBY mode (5 V range)

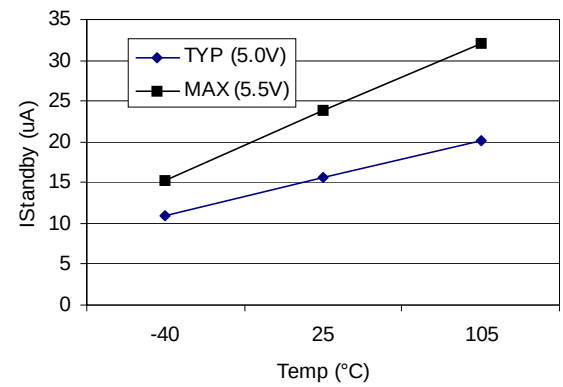


Table 16. Dual supply supply typical power consumption in Run, WFI, Slow and Slow-WFI modes

To calculate the power consumption in Dual supply mode, refer to the values given in *Table 15*. and consider that this consumption is split as follows:

$I_{DD(single\ supply)} \sim I_{DD(dual\ supply)} = I_{DD\_V18} + I_{DD(VDD\_IO)}$

For 3.3V range: $I_{DD(VDD\_IO)}$ ~ 1 to 2 mA

For 5V range: $I_{DD(VDD\_IO)}$ ~ 2 to 3 mA

Therefore most of the consumption is sunk on the V_{18} power supply

This formula does not apply in STOP and STANDBY modes, refer to *Table 17*.

Subject to general operating conditions for V_{DD_IO}, and T_A

Table 17. Typical power consumption in STOP and STANDBY modes

Symbol	Parameter	Conditions		3.3V Typ(1)	5V Typ(2)	Unit
I_{DD}(3)	Supply current in STOP mode(4)	LP_PARAM bits: ALL OFF(5)		12	15	µA
		LP_PARAM bits : MVREG ON, OSC4M OFF, FLASH OFF(6)		130	135	
		LP_PARAM bits: MVREG ON, OSC4M ON , FLASH OFF(6)		1950	1930	
		LP_PARAM bits: MVREG ON, OSC4M OFF, FLASH ON (6)		630	635	
		LP_PARAM bits: MVREG ON, OSC4M ON, FLASH ON (6)		2435	2425	
	Supply current in STOP mode(7)	LPPARAM bits: ALL OFF, with V_{18}=1.8 V	I_{DD_V18} I_{DD_V33}	5 <1	5 <1	µA
		LP_PARAM bits: OSC4M ON, FLASH OFF	I_{DD_V18} I_{DD_V33}	410 1475	410 1435	
		LP_PARAM bits: OSC4M OFF, FLASH ON	I_{DD_V18} I_{DD_V33}	550 <1	550 1	
		LP_PARAM bits: OSC4M ON, FLASH ON	I_{DD_V18} I_{DD_V33}	910 1475	910 1445	
	Supply current in STANDBY mode(4)	RTC OFF		11	14	µA
		RTC ON clocked by OSC32K		14	18	

1. Typical data are based on T_A=25°C, V_{DD_IO}=3.3 V and V_{18}=1.8 V unless otherwise indicated in the table.
2. Typical data are based on T_A=25°C, V_{DD_IO}=5.0 V and V_{18}=1.8 V unless otherwise indicated in the table.
3. The conditions for these consumption measurements are described at the beginning of *Section 6.3.4 on page 36*.
4. Single supply scheme see *Figure 12*.
5. In this mode, the whole digital circuitry is powered internally by the LPVREG at approximately 1.4 V, which significantly reduces the leakage currents.
6. In this mode, the whole digital circuitry is powered internally by the MVREG at 1.8 V.
7. Dual supply scheme see *Figure 13*.

XRTC1 external clock source

Subject to general operating conditions for V_{DD_IO}, and T_A.

Table 21. XRTC1 external clock source

Symbol	Parameter	Conditions(1)	Min	Typ	Max	Unit
f_{XRTC1}	External clock source frequency	see *Figure 20*		32.768	500	kHz
V_{XRTC1H}	XRTC1 input pin high level voltage		$0.7xV_{DD\_IO}$		V_{DD_IO}	V
V_{XRTC1L}	XRTC1 input pin low level voltage		V_{SS}		$0.3xV_{DD\_IO}$	
$t_{w(XRTC1H)}$ $t_{w(XRTC1L)}$	XRTC1 high or low time(2)		900			ns
$t_{r(XRTC1)}$ $t_{f(XRTC1)}$	XRTC1 rise or fall time(2)				50	
I_L	XRTCx Input leakage current	$V_{SS} \le V_{IN} \le V_{DD\_IO}$			±1	µA
$C_{IN(RTC1)}$	XRTC1 input capacitance(2)			5		pF
$DuCy_{(RTC1)}$	Duty cycle		30		70	%

1. Data based on typical application software.
2. Data based on design simulation and/or technology characteristics, not tested in production.

Figure 20. Typical application with an external clock source

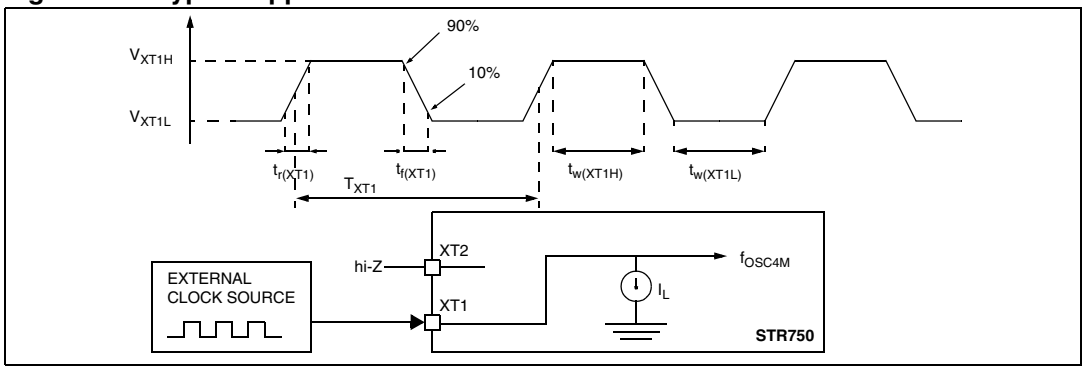


Figure 31. TI configuration - master mode, single transfer

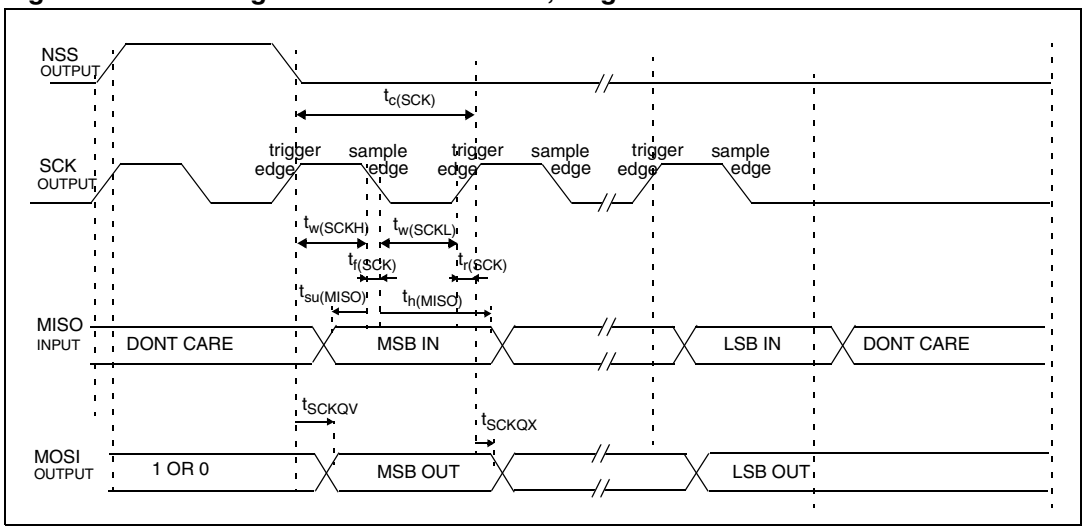
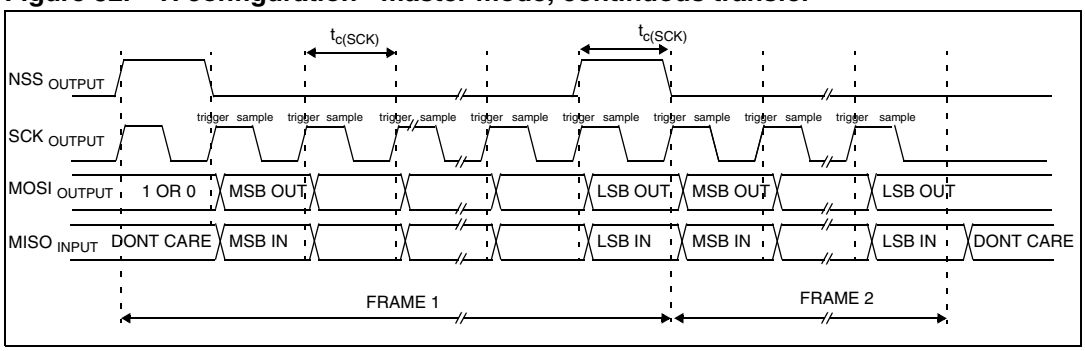


Figure 32. TI configuration - master mode, continuous transfer



SSP synchronous serial peripheral in slave mode (SPI or TI mode)

Subject to general operating conditions with $C_L \approx 45$ pF

Table 39. SSP slave mode characteristics(1)

Symbol	Parameter	Conditions		Min	Max	Unit
f_{SCK}	SPI clock frequency		SSP0		2.66 MHz (f_{PLCK}/12)	MHz
			SSP1			
$t_{su(NSS)}$	NSS input setup time w.r.t SCK first edge		SSP0	0		ns
			SSP1	0		
$t_{h(NSS)}$	NSS input hold time w.r.t SCK last edge		SSP0	t_{PCLK}+15ns		
			SSP1	t_{PCLK}+15ns		
t_{NSSLQV}	NSS low to Data Output MISO valid time		SSP0	$2t_{PCLK}$	$3t_{PCLK}$+30 ns	
			SSP1	$2t_{PCLK}$	$3t_{PCLK}$+30 ns	
t_{NSSLQZ}	NSS low to Data Output MISO invalid time		SSP0	$2t_{PCLK}$	$3t_{PCLK}$+15 ns	
			SSP1	$2t_{PCLK}$	$3t_{PCLK}$+15 ns	
t_{SCKQV}	SCK trigger edge to data output MISO valid time		SSP0		15	
			SSP1		30	
t_{SCKQX}	SCK trigger edge to data output MISO invalid time		SSP0	$2t_{PCLK}$		
			SSP1	$2t_{PCLK}$		
$t_{su(MOSI)}$	MOSI setup time w.r.t SCK sampling edge		SSP0	0		
			SSP1	0		
$t_{h(MOSI)}$	MOSI hold time w.r.t SCK sampling edge		SSP0	$3t_{PCLK}$+15 ns		
			SSP1	$3t_{PCLK}$+15 ns		

1. Data based on characterisation results, not tested in production.

Figure 33. SPI configuration, slave mode with CPHA=0, single transfer

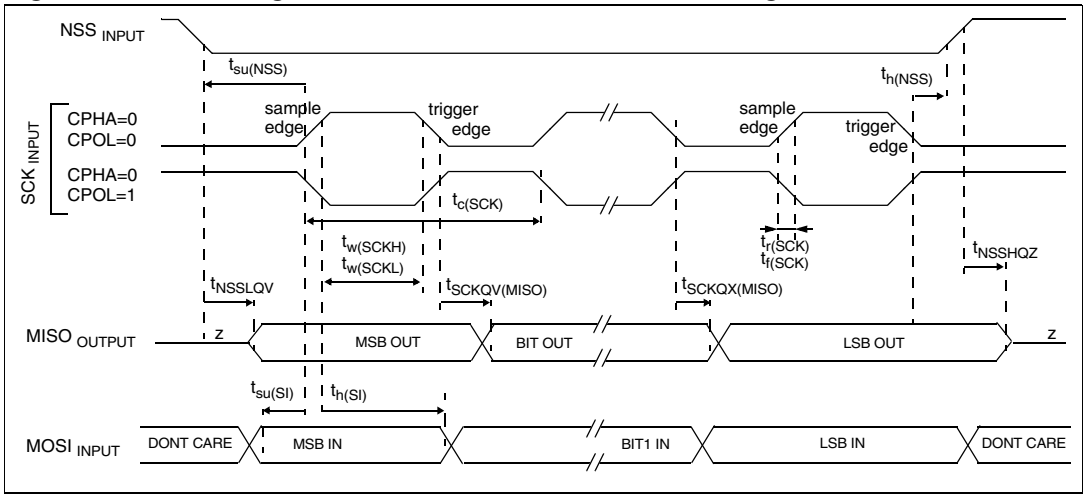


Figure 34. SPI configuration - slave mode with CPHA=0, continuous transfer

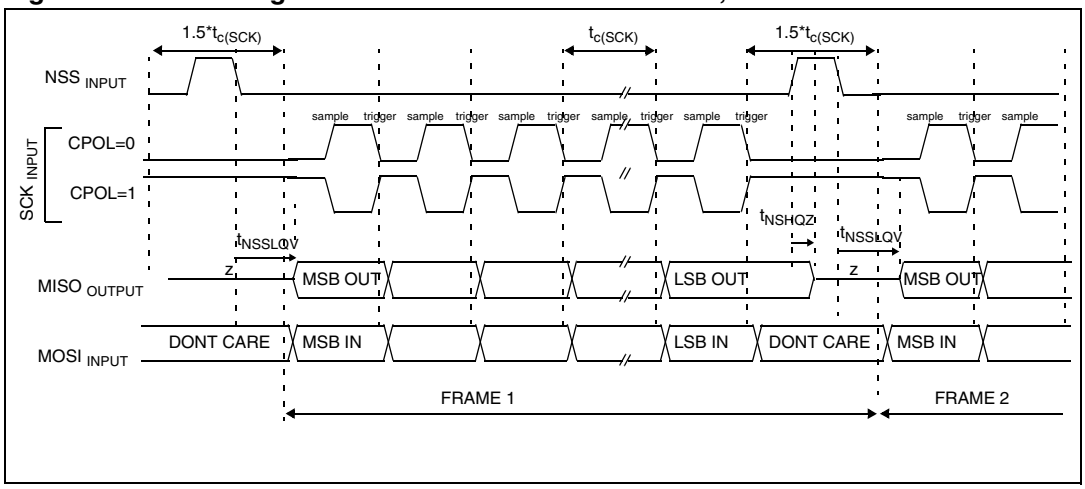


Figure 35. SPI configuration, slave mode with CPHA=1, single transfer

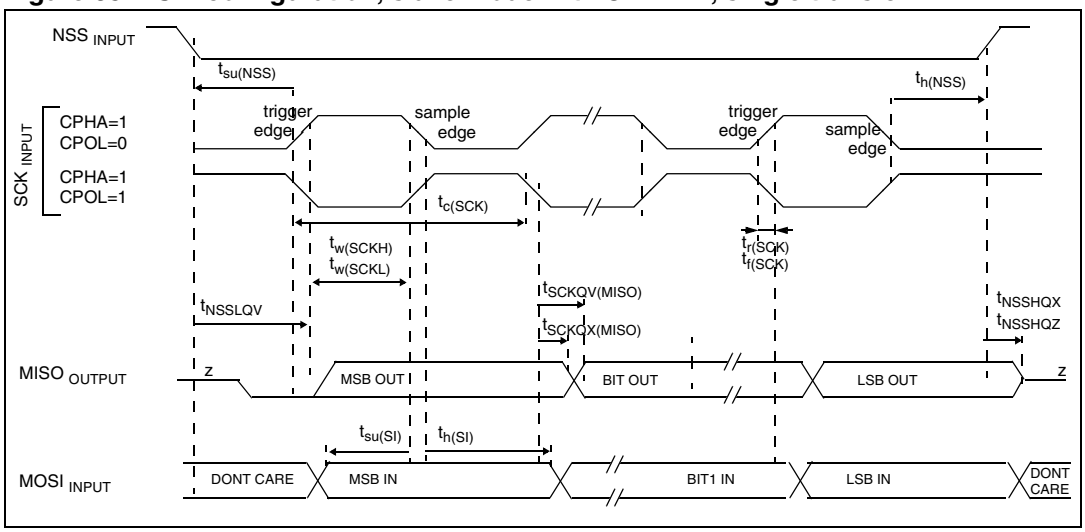
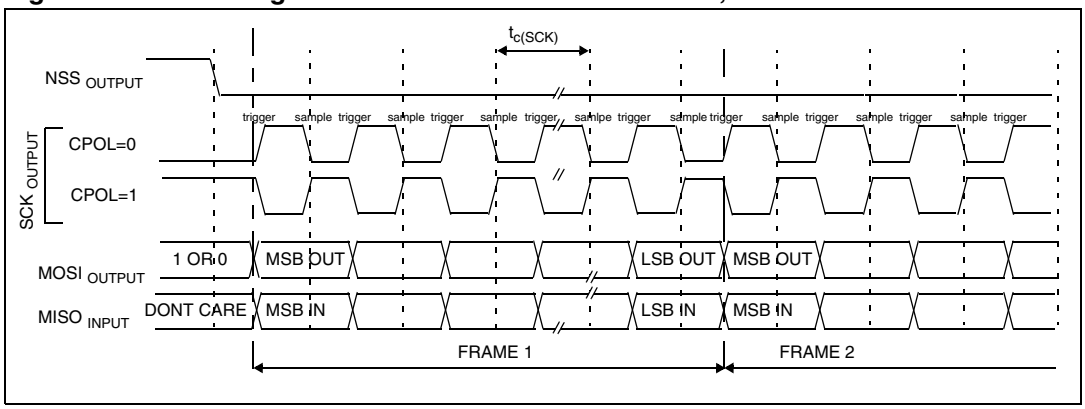


Figure 36. SPI configuration - slave mode with CPHA=1, continuous transfer



6.3.12 10-bit ADC characteristics

Subject to general operating conditions for V_{DDA_ADC}, f_{PCLK}, and T_A unless otherwise specified.

Table 45. 10-bit ADC characteristics

Symbol	Parameter	Conditions	Min	Typ(1)	Max	Unit
f_{ADC}	ADC clock frequency		0.4		8	MHz
V_{AIN}	Conversion voltage range(2)		V_{SSA_ADC}		V_{DDA_ADC}	V
R_{AIN}	External input impedance(3)(4)				10	kΩ
C_{AIN}	External capacitor on analog input(3)(4)				6.8	pF
I_{lkg}	Induced input leakage current	+400 µA injected on any pin			1	µA
		-400 µA injected on any pin except specific adjacent pins in *Table 46*			1	µA
		-400µA injected on specific adjacent pins in *Table 46*		40		µA
C_{ADC}	Internal sample and hold capacitor			3.5		pF
t_{CAL}	Calibration Time	f_{CK_ADC}=8 MHz	725.25			µs
			5802			$1/f_{ADC}$
t_{CONV}	Total Conversion time (including sampling time)	f_{CK_ADC}=8 MHz	3.75			µs
			30 (11 for sampling + 19 for Successive Approximation)			$1/f_{ADC}$
I_{ADC}		Sunk on V_{DDA_ADC}		3.7		mA

1. Unless otherwise specified, typical data are based on T_A=25°C. They are given only as design guidelines and are not tested.
2. Calibration is needed once after each power-up.
3. $C_{PARASITIC}$ represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (3 pF). A high $C_{PARASITIC}$ value will downgrade conversion accuracy. To remedy this, f_{ADC} should be reduced.
4. Depending on the input signal variation (f_{AIN}), C_{AIN} can be increased for stabilization time and reduced to allow the use of a larger serial resistor (R_{AIN}). It is valid for all f_{ADC} frequencies ≤ 8 MHz.

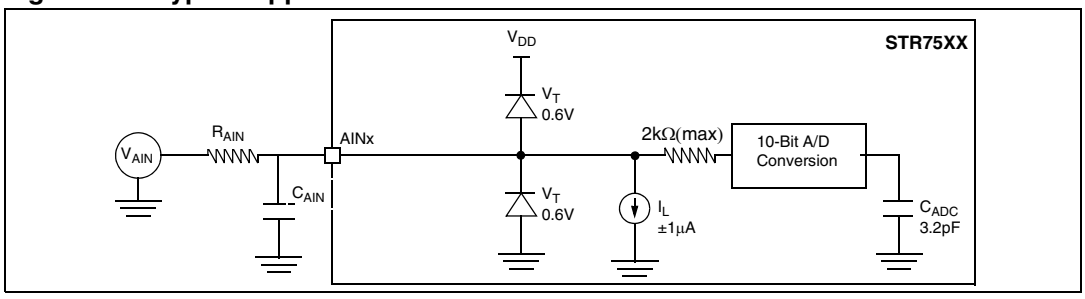
ADC accuracy vs. negative injection current

Injecting negative current on specific pins listed in *Table 46* (generally adjacent to the analog input pin being converted) should be avoided as this significantly reduces the accuracy of the conversion being performed. It is recommended to add a Schottky diode (pin to ground) to pins which may potentially inject negative current.

Table 46. List of adjacent pins

Analog input	Related adjacent pins
a	None
AIN1/P0.03	None
AIN2/P0.12	P0.11
AIN3/P0.17	P0.18 and P0.16
AIN4/P0.19	P0.24
AIN5/P0.22	None
AIN6/P0.23	P2.04
AIN7/P0.27	P1.11 and P0.26
AIN8/P0.29	P0.30 and P0.28
AIN9/P1.04	None
AIN10/P1.06	P1.05
AIN11/P1.08	P1.04 and P1.13
AIN12/P1.11	P2.17 and P0.27
AIN13/P1.12	None
AIN14/P1.13	P1.14 and P1.01
AIN15/P1.14	None

Figure 42. Typical application with ADC



Analog power supply and reference pins

The V_{DDA_ADC} and V_{SSA_ADC} pins are the analog power supply of the A/D converter cell.

Separation of the digital and analog power pins allow board designers to improve A/D performance. Conversion accuracy can be impacted by voltage drops and noise in the event of heavily loaded or badly decoupled power supply lines (see *: General PCB design guidelines on page 74*).

Table 47. ADC accuracy

ADC accuracy with f_{CK_SYS} = 20 MHz, f_{ADC}=8 MHz, R_{AIN} < 10 kΩ This assumes that the ADC is calibrated(1)					
Symbol	**Parameter**	**Conditions**	**Typ**	**Max**	**Unit**
$\|E_T\|$	Total unadjusted error (2) (3)	V_{DDA_ADC}=3.3 V	1	1.2	LSB
		V_{DDA_ADC}=5.0 V	1	1.2	
$\|E_O\|$	Offset error(2) (3)	V_{DDA_ADC}=3.3 V	0.15	0.5	
		V_{DDA_ADC}=5.0 V	0.15	0.5	
E_G	Gain Error (2) (3)	V_{DDA_ADC}=3.3 V	-0.8	-0.2	
		V_{DDA_ADC}=5.0 V	-0.8	-0.2	
$\|E_D\|$	Differential linearity error(2) (3)	V_{DDA_ADC}=3.3 V	0.7	0.9	
		V_{DDA_ADC}=5.0 V	0.7	0.9	
$\|E_L\|$	Integral linearity error (2) (3)	V_{DDA_ADC}=3.3 V	0.6	0.8	
		V_{DDA_ADC}=5.0 V	0.6	0.8	

1. Calibration is needed once after each power-up.
2. Refer to *ADC accuracy vs. negative injection current on page 73*
3. ADC Accuracy vs. MCO (Main Clock Output): the ADC accuracy can be significantly degraded when activating the MCO on pin P0.01 while converting an analog channel (especially those which are close to the MCO pin). To avoid this, when an ADC conversion is launched, it is strongly recommended to disable the MCO.

Figure 44. ADC accuracy characteristics

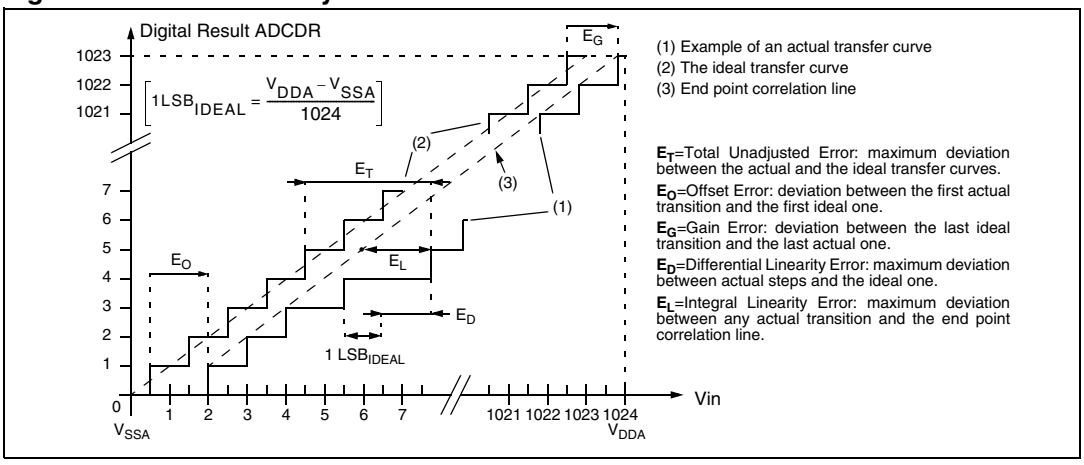
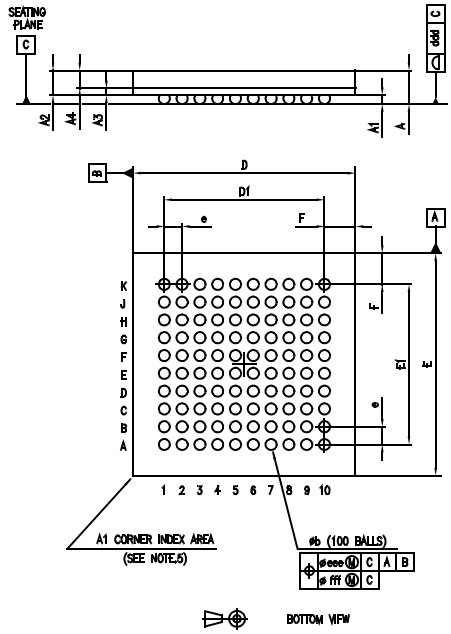


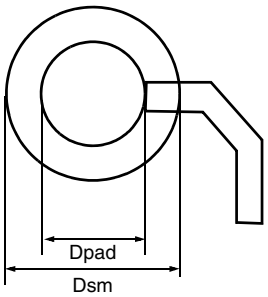
Figure 48. 100-ball low profile fine pitch ball grid array package



Dim.	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A			1.700			0.0669
A1	0.270			0.0106		
A2		1.085			0.0427	
A3		0.30			0.0118	
A4			0.80			0.0315
b	0.45	0.50	0.55	0.0177	0.0197	0.0217
D	9.85	10.00	10.15	0.3878	0.3937	0.3996
D1		7.20			0.2835	
E	9.85	10.00	10.15	0.3878	0.3937	0.3996
E1		7.20			0.2835	
e		0.80			0.0315	
F		1.40			0.055	
ddd			0.12			0.005
eee			0.15			0.006
fff			0.08			0.003
	Number of Balls					
N	100					

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 49. Recommended PCB design rules (0.80/0.75mm pitch BGA)



Dpad	0.37 mm
Dsm	0.52 mm typ. (depends on solder mask registration tolerance
Solder paste	0.37 mm aperture diameter
– Non solder mask defined pads are recommended – 4 to 6 mils screen print	

9 Revision history

Table 50. Document revision history

Date	Revision	Description of Changes
25-Sep-2006	1	Initial release
30-Oct-2006	2	Added power consumption data for 5V operation in *Section 6*
04-Jul-2007	3	Changed datasheet title from STR750F to STR750FXX STR751Fxx STR752Fxx STR755xx. Added *Table 1: Device summary on page 1* Added note 1 to *Table 6* Added STOP mode IDD max. values in *Table 14* Updated XT2 driving current in *Table 23.* Updated RPD in *Table 32* Updated *Table 21: XRTC1 external clock source on page 45* Updated *Table 34: Output speed on page 57* Added characteristics for *SSP synchronous serial peripheral in master mode (SPI or TI mode) on page 62* and *SSP synchronous serial peripheral in slave mode (SPI or TI mode) on page 65* Added characteristics for *SMI - serial memory interface on page 68* Added *Table 42: USB startup time on page 70*
23-Oct-2007	4	Updated *Section 6.2.3: Thermal characteristics on page 33* Updated P_D, T_J and T_A in *Section 6.3: Operating conditions on page 34* Updated *Table 20: XT1 external clock source on page 44* Updated *Table 21: XRTC1 external clock source on page 45* Updated *Section 7: Package characteristics on page 76* (inches rounded to 4 decimal digits instead of 3) Updated Ordering information *Section 8: Order codes on page 81*
17-Feb-2009	5	Modified note 3 below *Table 8: Current characteristics on page 33* Added AHB clock frequency for write access to Flash registers in *Table 10: General operating conditions on page 34* Modified note 3 below *Table 41: SDA and SCL characteristics on page 69*